

Code: AE05

Subject: BASIC ELECTRONICS

AMETE – CS/IT (OLD SCHEME)

Time: 3 Hours

JUNE 2012

Max. Marks: 100

PLEASE WRITE YOUR ROLL NO. AT THE SPACE PROVIDED ON EACH PAGE IMMEDIATELY AFTER RECEIVING THE QUESTION PAPER.

NOTE: There are 9 Questions in all.

- Question 1 is compulsory and carries 20 marks. Answer to Q.1 must be written in the space provided for it in the answer book supplied and nowhere else.
- The answer sheet for the Q.1 will be collected by the invigilator after 45 minutes of the commencement of the examination.
- Out of the remaining EIGHT Questions answer any FIVE Questions. Each question carries 16 marks.
- Any required data not explicitly given, may be suitably assumed and stated.

Q.1 Choose the correct or best alternative in the following: (2×10)

- a. The intersection of a V-I curve with the load line is called the
- (A) Transfer curve (B) transition point
(C) Load point (D) Q-point
- b. If a single diode in a center tapped full-wave rectifier opens, the output is
- (A) 0 V (B) half wave rectified
(C) Reduced in amplitude (D) unaffected
- c. The purpose of a small capacitor placed across the output of an IC regulator is to
- (A) Improve transient response
(B) couple the output signal to the load
(C) Filter the ac
(D) protect the IC regulator
- d. When the collector resistor in a CE amplifier is increased in value, the voltage gain
- (A) Increases (B) decreases
(C) Is not affected (D) becomes erratic
- e. A type of transistor that is normally ON when the gate to source voltage is zero is
- (A) JFET (B) D-MOSFET
(C) E-MOSFET (D) ALL of them.
- f. Cross over distortion is a problem for
- (A) Class A amplifiers (B) Class AB amplifiers

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g. The output of a particular op-amp increases 8V in 12 μ s the slew rate is

- (A) 96 V/ μ s (B) 0.67 V/ μ s
(C) 1.5 V/ μ s (D) none of these.

h. In Integrator, the feedback element is a

- (A) Resistor (B) Capacitor
(C) Diode (D) Inductor

i. Wein-bridge oscillations are based on

- (A) Positive feedback (B) negative feedback
(C) The piezoelectric effect (D) high gain

j. In a basic series regulator, V_{OUT} is determined by

- (A) the control element (B) the sample circuit
(C) the reference voltage (D) answers (B) and (C).

Answer any FIVE Questions out of EIGHT Questions.
Each question carries 16 marks.

- Q.2** a. The Si Darlington transistor pair of Fig. 1 has negligible leakage current, and $\beta_1 = \beta_2 = 50$. Let $V_{CC} = 12V$; $R_E = 1 k\Omega$, and $R_2 \rightarrow \infty$. (i) Find the value of R_1 needed to bias the circuit so that $V_{CEQ2} = 6V$. (ii) With R_1 as found in part a, find V_{CEQ1} . (8)

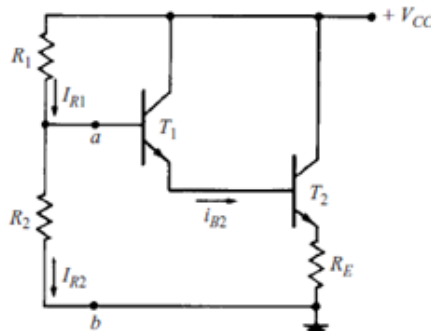
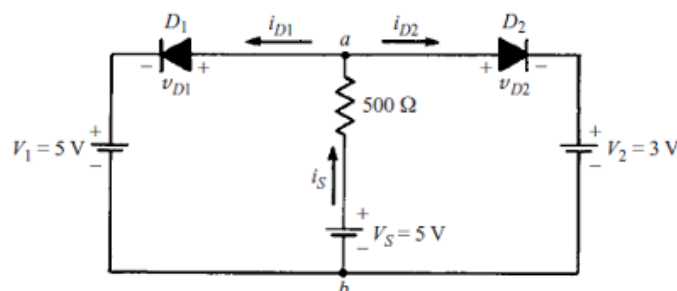


Fig. 1

- b. What is load line? Discuss why ac load line differs from the dc load line. Draw the ac load line for a CE configuration amplifier and find the Q-point. (8)

- Q.3** a. In the circuit of Fig. 2, Diodes D_1 and D_2 are ideal diodes. Find I_{D1} and I_{D2} . (8)



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- b. A Zener diode has the specifications $V_Z = 5.2 \text{ V}$ and $P_{Dmax} = 260 \text{ mW}$. Assume $R_Z = 0$ (i) Find the maximum allowable current i_Z when the Zener diode is acting as a regulator. (ii) If a single-loop circuit consists of an ideal 15-V dc source V_S , a variable resistor R , and the described Zener diode, find the range of values of R for which the Zener diode remain in constant reverse breakdown with no danger of failure. (8)

- Q.4 a. Describe the construction and operation of JFET's. Explain the parameters g_m , I_{DSS} , I_{GSS} , $V_{GS(OFF)}$ and V_P . Describe the transconductance curve for a JFET and explain how it relates to the drain characteristic curve. (8)

- b. Explain the operation of a class B push pull power amplifier with a neat circuit diagram and waveforms. Determine its collector efficiency. What is cross over distortion and how do you eliminate it in the above power amplifier? (8)

- Q.5 a. An amplifier has a voltage gain of 4000. It's input impedance is 2 K ohm and output impedance is 60 K ohm. Calculate the voltage gain, input and output impedance of the circuit if 5% of the feedback is fed in the form of series negative voltage feedback. (8)

- b. Find the relationship between v_o and v_i in the circuit of Fig. 3. (8)

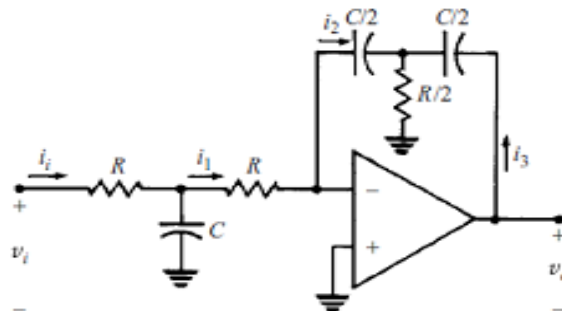
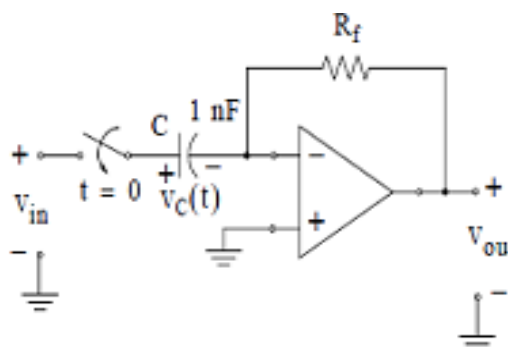


Fig. 3

- Q.6 a. The time constant of the differentiator circuit of Fig.4 is $\tau = 1 \text{ ms}$, and $v_c(0^-) = 0$
- Find the value of the feedback resistor R_f .
 - Derive the transfer function.
 - Find the magnitude and phase at $f = 1 \text{ kHz}$
 - If a resistor is added in series with the capacitor to limit the high frequency gain to 100, what should be the value of that resistor?

(10)



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- b. For the Schmitt trigger circuit of Fig. 5(a) below, the input signal v_s is as shown in Fig 5(b), find and sketch V_{+upper} and V_{+lower} . (6)

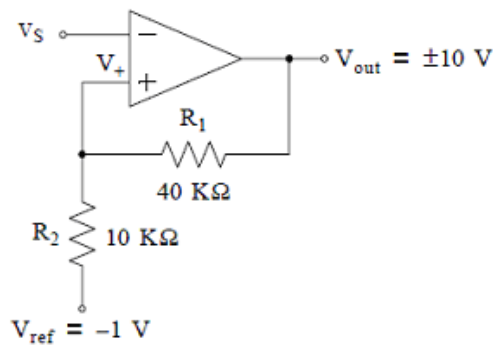


Fig. 5(a)

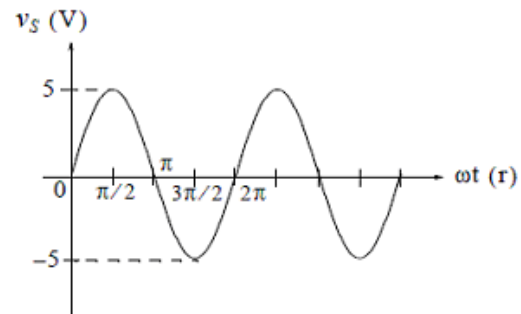


Fig. 5(b)

- Q.7**
- Explain the use of an external pass transistor and current limiting in IC voltage regulator. (8)
 - Implement the JK FF using NAND GATES ONLY. (8)
- Q.8**
- Prove that for a Wien Bridge oscillator the gain of amplifier should equal to δ i.e deviation where $\delta > 3$. Also derive expression for frequency of oscillation with suitable diagram (8)
 - A combinational logic circuit is required which produces an output D from four input signals $A, B, C1$ and $C2$ according to the following rules.
 - If $C1$ and $C2$ are both 1, the output D must be 0.
 - If $C1$ and $C2$ are both 0 the output D must be 1.
 - If $C1=1$ and $C2=0$, then output D must be equal to input A .
 - If $C1=0$ and $C2=1$, then output D must be equal to input B .
 - Construct the truth table for D .
 - Construct the Karnaugh map for D .
 - By combining 1s in the largest possible groups on the Karnaugh map, obtain an expression for D in the simplest sum-of-products form.
 - Draw the gate implementation of the logic circuit to generate the output D using AND gate, OR gates and inverters. (8)
- Q.9** Write short note on any TWO:
- 555 timer
 - Transistor biasing techniques
 - MOSFET. (2×8)